NSN 5961-01-422-7397

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-422-7397 **Inclosure Material:** Metal **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5000.0 reverse voltage, peak **Current Rating Per Characteristic:** 70.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 66948-2001073 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli